

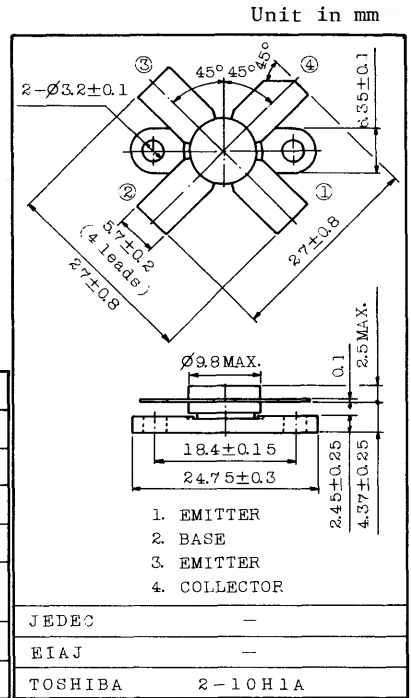
UHF BAND POWER AMPLIFIER APPLICATIONS.

FEATURES:

- Output Power : $P_O=3W$ (Min.)
($f=470MHz$, $V_{CC}=12.6V$, $P_i=0.4W$)
- 100% Tested for Load Mismatch Stress at All Phase Angles with 30:1 VSWR @ $V_{CC}=15V$, $P_i=0.4W$, $f=470MHz$

MAXIMUM RATINGS ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	35	V
Collector-Emitter Voltage	V_{CEO}	17	V
Emitter-Base Voltage	V_{EBO}	3.5	V
Collector Current	I_C	0.8	A
Collector Power Dissipation ($T_c=25^\circ C$)	P_C	7.5	W
Junction Temperature	T_j	175	$^\circ C$
Storage Temperature Range	T_{stg}	-65 ~ 175	$^\circ C$



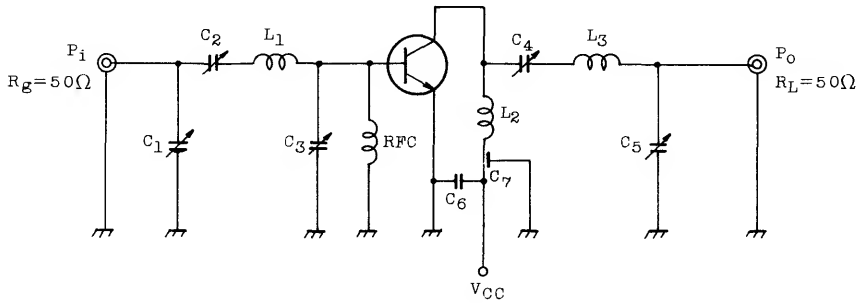
Weight : 4g

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=15V, I_E=0$	-	-	1	mA
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=1mA, I_E=0$	35	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=5mA, I_B=0$	17	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=0.1mA, I_C=0$	3.5	-	-	V
DC Current Gain	h_{FE}	$V_{CE}=5V, I_C=0.5A$	10	-	-	
Collector Output Capacitance	C_{ob}	$V_{CB}=10V, I_E=0, f=1MHz$	-	-	20	pF
Output Power	P_O	(Fig.)	3	-	-	W
Power Gain	G_{pe}	$V_{CC}=12.6V, f=470MHz,$ $P_i=0.4W$	4.7	-	-	dB
Collector Efficiency	η_c		50	-	-	%
Series Equivalent Input Impedance	Z_{IN}	$V_{CC}=12.6V, f=470MHz,$ $P_O=3W$	-	$1.7 + j3.2$	-	Ω
Series Equivalent Output Impedance	Z_{OUT}		-	$5.6 - j7.5$	-	Ω

2SC2391

Fig. $f=470\text{MHz}$ P_o TEST CIRCUIT



C_1, C_2, C_3 : $\sim 10\text{pF}$

C_4, C_5 : $\sim 30\text{pF}$

C_6 : $0.02\mu\text{F}$

C_7 : 1000pF FEED THROUGH

L_1 : $\phi 1.6$ SILVER PLATED COPPER WIRE, 7ID, $\frac{1}{2}T$

L_2 : $\phi 1.2$ SILVER PLATED COPPER WIRE, 10ID, $\frac{1}{2}T$

L_3 : $\phi 1.6$ SILVER PLATED COPPER WIRE, 10ID, $\frac{1}{2}T$

RFC : $\phi 0.7$ ENAMEL COATED COPPER WIRE, 3ID, 5T

